# **Small Signal MOSFET**

20 V, Dual N–Channel, SC–88 ESD Protection

### Features

- Small Footprint (2 x 2 mm)
- Low Gate Charge N–Channel Device
- ESD Protected Gate
- Same Package as SC-70 (6 Leads)
- Pb–Free Packages are Available

## Applications

- Load Power switching
- Li-Ion Battery Supplied Devices
- Cell Phones, Media Players, Digital Cameras, PDAs
- DC–DC Conversion

### **MAXIMUM RATINGS** (T<sub>J</sub> = $25^{\circ}$ C unless otherwise stated)

Param	Symbol	Value	Units			
Drain-to-Source Voltage	V <sub>DSS</sub>	20	V			
Gate-to-Source Voltage	V <sub>GS</sub>	±12	V			
Continuous Drain Current	Steady State	$T_A = 25^{\circ}C$	I <sub>D</sub>	0.63	А	
(Based on $R_{\theta JA}$ )	Sidle	$T_A = 85^{\circ}C$		0.46		
Power Dissipation	Steady State	$T_A = 25^{\circ}C$	PD	0.27	W	
(Based on $R_{\theta JA}$ )	Siale	$T_A = 85^{\circ}C$		0.14		
Continuous Drain Current	Steady State	$T_A = 25^{\circ}C$	Ι <sub>D</sub>	0.91	А	
(Based on R <sub>0JL</sub> )	Sidle	$T_A = 85^{\circ}C$	1	0.65		
Power Dissipation	Steady	$T_A = 25^{\circ}C$		0.55	W	
(Based on $R_{\theta JL}$ )	State	$T_A = 85^{\circ}C$	PD	0.29		
Pulsed Drain Current $t \le 10 \ \mu s$			I <sub>DM</sub>	±1.2	А	
Operating Junction and Storage Temperature			T <sub>J</sub> , T <sub>STG</sub>	–55 to 150	°C	
Continuous Source Current (Body Diode)			۱ <sub>S</sub>	0.63	А	
Lead Temperature for Soldering Purposes (1/8" from case for 10 s)			ΤL	260	°C	

### THERMAL RESISTANCE RATINGS (Note 1)

Parameter	Symbol	Тур	Max	Units
Junction-to-Ambient - Steady State	$R_{\thetaJA}$	400	460	°C/W
Junction-to-Lead (Drain) - Steady State	$R_{\theta JL}$	194	226	

Stresses exceeding Maximum Ratings may damage the device. Maximum Ratings are stress ratings only. Functional operation above the Recommended Operating Conditions is not implied. Extended exposure to stresses above the Recommended Operating Conditions may affect device reliability.

1. Surface mounted on FR4 board using 1 oz Cu area = 0.9523 in sq.

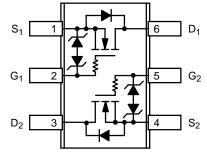


## **ON Semiconductor®**

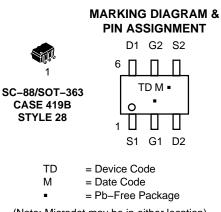
## http://onsemi.com

V <sub>(BR)DSS</sub>	R <sub>DS(on)</sub> Тур	I <sub>D</sub> Max
	0.22 Ω @ 4.5 V	
8 V	0.32 Ω @ 2.5 V	0.775 A
	0.51 Ω @ 1.8 V	





Top View



(Note: Microdot may be in either location)

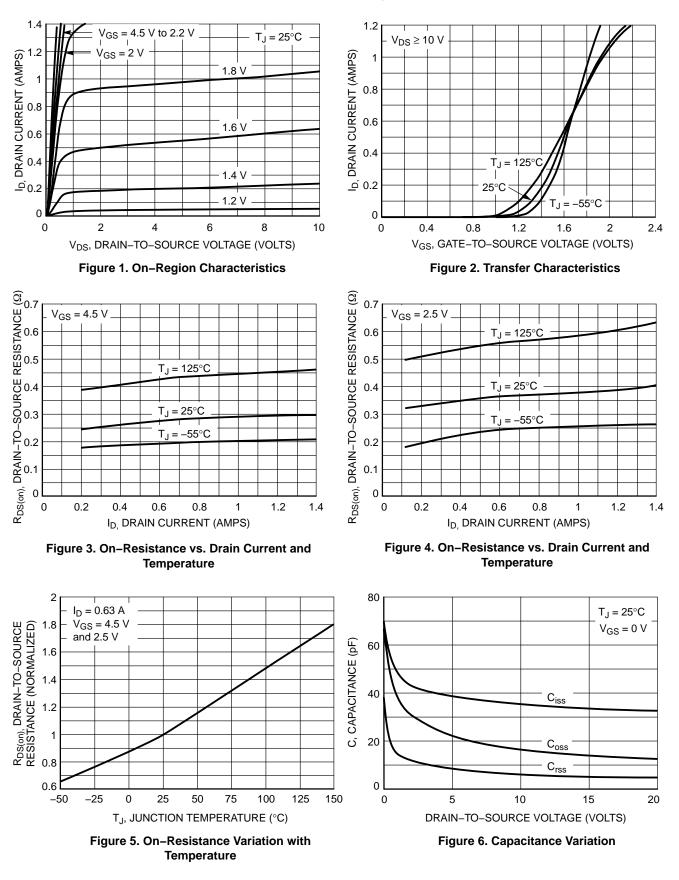
## **ORDERING INFORMATION**

See detailed ordering and shipping information in the package dimensions section on page 4 of this data sheet.

## **ELECTRICAL CHARACTERISTICS** (T<sub>J</sub> = $25^{\circ}$ C unless otherwise stated)

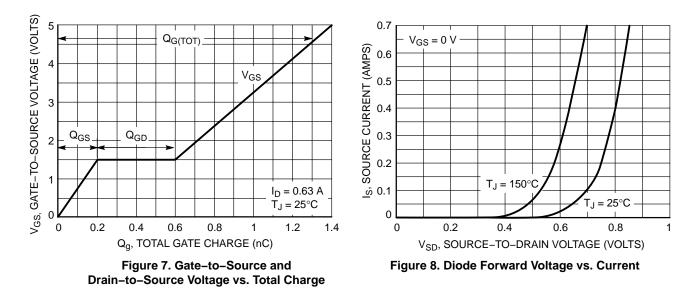
Parameter	Symbol	Test Condition		Min	Тур	Max	Unit	
OFF CHARACTERISTICS	•				•	1		
Drain-to-Source Breakdown Voltage	V <sub>(BR)DSS</sub>	$V_{GS} = 0 \text{ V}, \text{ I}_{D} = 250 \ \mu\text{A}$		20	27		V	
Drain-to-Source Breakdown Voltage Temperature Coefficient	V <sub>(BR)DSS</sub> /T <sub>J</sub>				22		mV/ °C	
Zero Gate Voltage Drain Current	I <sub>DSS</sub>	V <sub>GS</sub> = 0 V, V <sub>E</sub>	<sub>DS</sub> = 16 V			1.0	μΑ	
Gate-to-Source Leakage Current	I <sub>GSS</sub>	$V_{DS} = 0 V, V_{GS} = \pm 12 V$				10	μA	
ON CHARACTERISTICS (Note 2)								
Gate Threshold Voltage	V <sub>GS(TH)</sub>	$V_{GS} = V_{DS}, I_D$	= 250 μA	0.6	0.92	1.5	V	
Gate Threshold Temperature Coefficient	V <sub>GS(TH)</sub> /T <sub>J</sub>				-2.1		mV/ °C	
Drain-to-Source On Resistance	R <sub>DS(on)</sub>	V <sub>GS</sub> = 4.5 V, I <sub>D</sub> = 0.63 A			0.29	0.375	Ω	
		V <sub>GS</sub> = 2.5 V, I <sub>E</sub>	<sub>D</sub> = 0.40 A		0.36	0.445	1	
Forward Transconductance	9fs	V <sub>DS</sub> = 4.0 V, I <sub>D</sub> = 0.63 A			2.0		S	
CHARGES AND CAPACITANCES								
Input Capacitance	C <sub>ISS</sub>				33	46	pF	
Output Capacitance	C <sub>OSS</sub>	V <sub>GS</sub> = 0 V, f = 1.0 MHz, V <sub>DS</sub> = 20 V			13	22		
Reverse Transfer Capacitance	C <sub>RSS</sub>				2.8	5.0		
Total Gate Charge	Q <sub>G(TOT)</sub>	$V_{GS} = 4.5 \text{ V}, V_{DS} = 10 \text{ V},$ $I_D = 0.63 \text{ A}$			1.3	3.0	nC	
Threshold Gate Charge	Q <sub>G(TH)</sub>				0.1			
Gate-to-Source Charge	Q <sub>GS</sub>				0.2			
Gate-to-Drain Charge	Q <sub>GD</sub>				0.4			
SWITCHING CHARACTERISTICS (No	ote 3)							
Turn–On Delay Time	td <sub>(ON)</sub>				0.083		μs	
Rise Time	tr	$V_{GS}$ = 4.5 V, $V_{DD}$ = 10 V, $I_{D}$ = 0.5 A, $R_{G}$ = 20 $\Omega$			0.227		1	
Turn–Off Delay Time	td <sub>(OFF)</sub>				0.786			
Fall Time	tf				0.506			
DRAIN-SOURCE DIODE CHARACTE	RISTICS				•	•		
Forward Diode Voltage	V <sub>SD</sub>	V <sub>GS</sub> = 0 V,	$T_J = 25^{\circ}C$		0.76	1.1	V	
	I <sub>S</sub> =0	I <sub>S</sub> =0.23 A	T <sub>J</sub> = 125°C		0.63		1	
Reverse Recovery Time	t <sub>RR</sub>	$V_{GS} = 0 \text{ V}, \text{ dI}_S/\text{dt}$ $I_S = 0.63$	= 100 A/μs, 3 A		0.410		μs	

Pulse Test: pulse width ≤ 300 μs, duty cycle ≤ 2%.
Switching characteristics are independent of operating junction temperatures.



## TYPICAL PERFORMANCE CURVES (T<sub>J</sub> = $25^{\circ}$ C unless otherwise noted)

## **TYPICAL PERFORMANCE CURVES** (T<sub>J</sub> = 25°C unless otherwise noted)



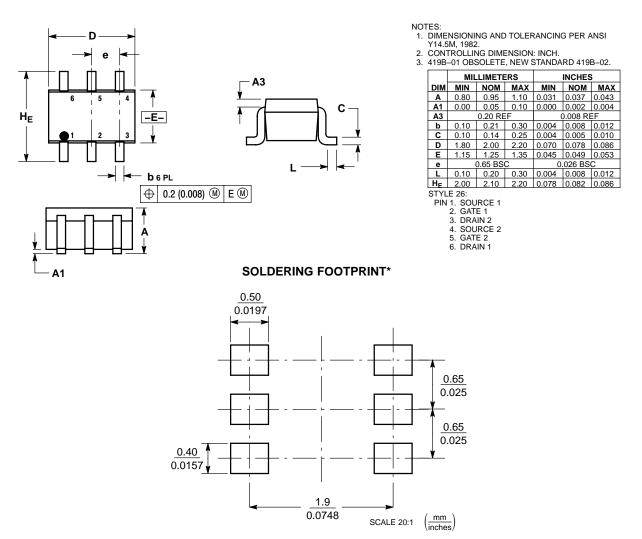
#### **ORDERING INFORMATION**

Device	Package	Shipping <sup>†</sup>
NTJD4401NT1	SC-88	3000 / Tape & Reel
NTJD4401NT1G	SC-88 (Pb-Free)	3000 / Tape & Reel
NTJD4401NT2	SC-88	3000 / Tape & Reel
NTJD4401NT2G	SC-88 (Pb-Free)	3000 / Tape & Reel
NTJD4401NT4	SC-88	10,000 / Tape & Reel
NTJD4401NT4G	SC-88 (Pb-Free)	10,000 / Tape & Reel

<sup>†</sup>For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specifications Brochure, BRD8011/D.

#### PACKAGE DIMENSIONS

SC-88/SC70-6/SOT-363 CASE 419B-02 ISSUE W



\*For additional information on our Pb–Free strategy and soldering details, please download the ON Semiconductor Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

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